

I2152 rev. A 01/2000

International IOR Rectifier

QUIETIR 85EPF.. Series

FAST SOFT RECOVERY
RECTIFIER DIODE



$I_{F(RMS)} = 160 \text{ A}$
 $V_F < 1.35 \text{ V @ } 100 \text{ A}$
 $t_{rr} = 70 \text{ nsec}$
 $V_{RRM} \text{ 200 to } 600 \text{ V}$

Major Ratings and Characteristics

Characteristics	85EPF..	Units
$I_{F(AV)}$ Rect. Conduction 50% duty Cycle @ $T_C = 85^\circ \text{C}$	85	A
$I_{F(RMS)}$	160	A
V_{RRM} range (*)	200 to 600	V
I_{FSM}	1100	A
V_F @ 100 A, $T_J = 25^\circ \text{C}$	1.35	V
t_{rr} @ 1 A, -100 A/ μs	70	ns
T_J range	-40 to 150	$^\circ \text{C}$

Description/Features

The 85EPF.. fast soft recovery QUIETIR rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature stable and power cycling conditions.

Available in the new PowIRtab™ package, this new series is suitable for a large range of applications combining excellent die to footprint ratio and sturdiness connectivity for use in high current environments.

Typical applications are both:

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met.

Case Styles



(*) for higher voltage up to 1600V contact factory

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Voltage Ratings

Part Number	V_{RRM} , maximum peak reverse voltage V	V_{RSM} , maximum non repetitive peak reverse voltage V	I_{RRM} 150°C mA
85EPF02	200	300	20
85EPF04	400	500	
85EPF06	600	700	

Absolute Maximum Ratings

Parameters	85EPF..	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	85	A	@ $T_C = 75^\circ\text{C}$, 180° conduction half sine wave
I_{FSM} Max. Peak One Cycle Non Repetitive Surge Current	1100	A	10ms Sine pulse, rated V_{RRM} applied
	1250		10ms Sine pulse, no voltage reapplied
I^2t Max. I^2t for fusing	5000	A^2s	10ms Sine pulse, rated V_{RRM} applied
	7000		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	70000	$\text{A}^2\sqrt{\text{s}}$	$t = 0.1$ to 10ms, no voltage reapplied

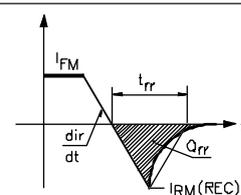
Electrical Specifications

Parameters	85EPF..	Units	Conditions
V_{FM} Max. Forward Voltage Drop	1.3	V	@ 85A, $T_J = 25^\circ\text{C}$
r_t Forward slope resistance	4.07	$\text{m}\Omega$	$T_J = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.8	V	
I_{RM} Max. Reverse Leakage Current	0.1	mA	$T_J = 25^\circ\text{C}$
	20		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

Recovery Characteristics

Parameters	85EPF..	Units	Conditions
t_{rr} Reverse Recovery Time	190	ns	$I_F @ 85\text{Apk}$ @ 25A/ μs @ 25°C
I_{rr} Reverse Recovery Current	3.5	A	
Q_{rr} Reverse Recovery Charge	0.6	μC	
S Snap Factor	0.5		



Thermal-Mechanical Specifications

Parameters	85EPF..	Units	Conditions
T _J Max. Junction Temperature Range	-40to150	°C	
T _{stg} Max. Storage Temperature Range	-40to150	°C	
R _{thJC} Max. Thermal Resistance Junction to Case	0.35	°C/W	DC Operation
R _{thJA} Max. Thermal Resistance Junction to Ambient	40	°C/W	
R _{thCS} Typical Thermal Resistance, Case to Heatsink	0.2	°C/W	Mounting surface, smooth and greased
wt Approximate Weight	6(0.21)	g (oz.)	
T Mounting Torque	Min.	6(5)	Kg-cm (lbf-in)
	Max.	12(10)	
Case Style	PowIRtab™		

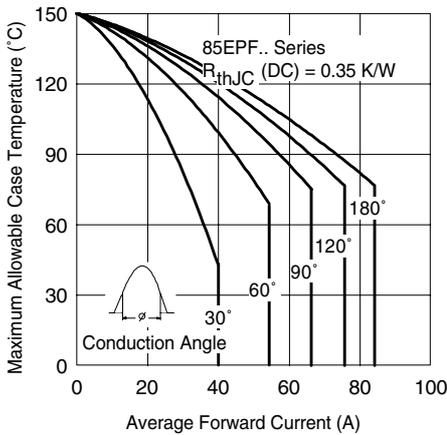


Fig.1 - Current Rating Characteristics

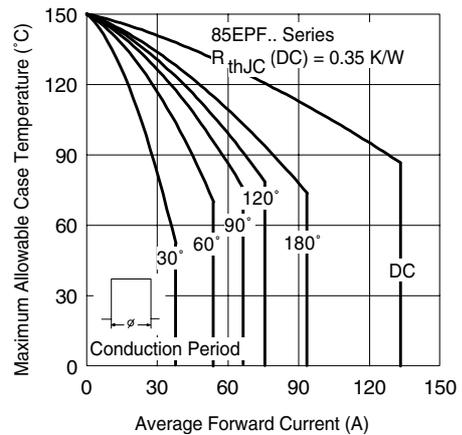


Fig.2 - Current Rating Characteristics

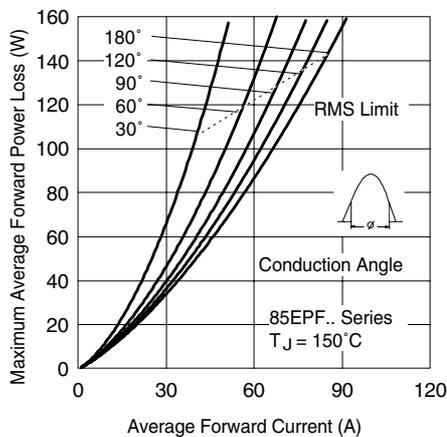


Fig.3 - Forward Power Loss Characteristics

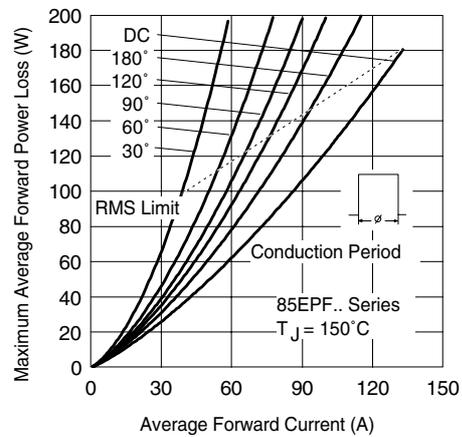


Fig.4 - Forward Power Loss Characteristics

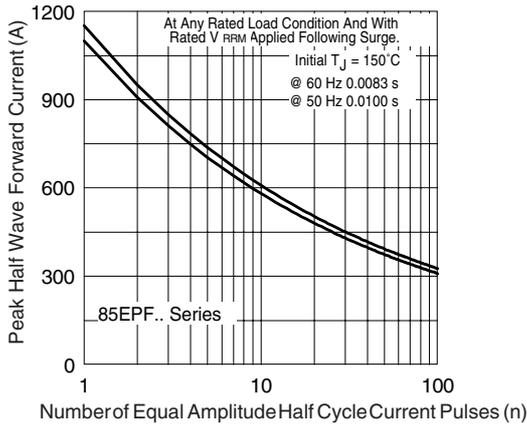


Fig. 5 - Maximum Non-Repetitive Surge Current

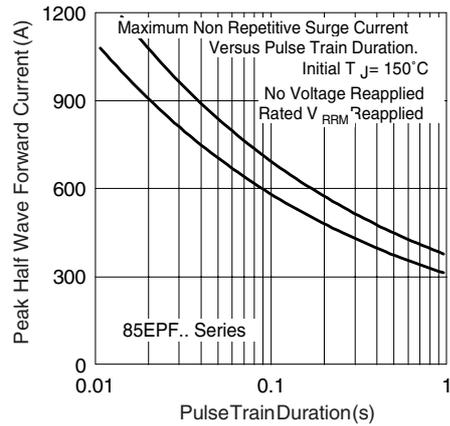


Fig. 6 - Maximum Non-Repetitive Surge Current

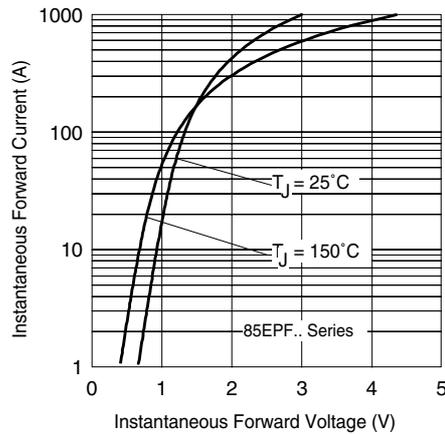


Fig. 7 - Forward Voltage Drop Characteristics

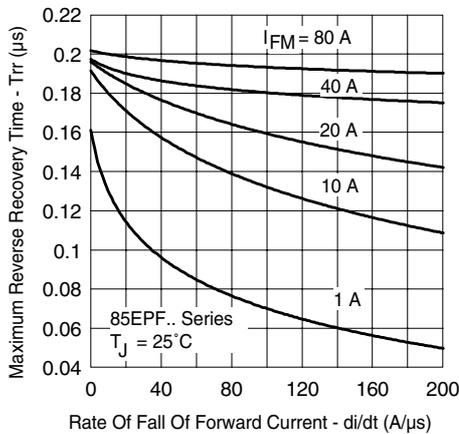


Fig. 8 - Recovery Time Characteristics, $T_J = 25^\circ\text{C}$

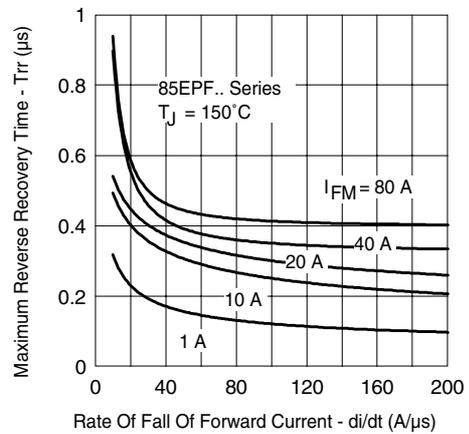


Fig. 9 - Recovery Time Characteristics, $T_J = 150^\circ\text{C}$

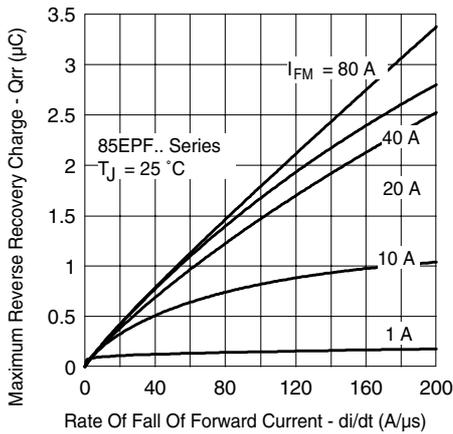


Fig. 10 - Recovery Charge Characteristics, $T_J = 25^\circ\text{C}$

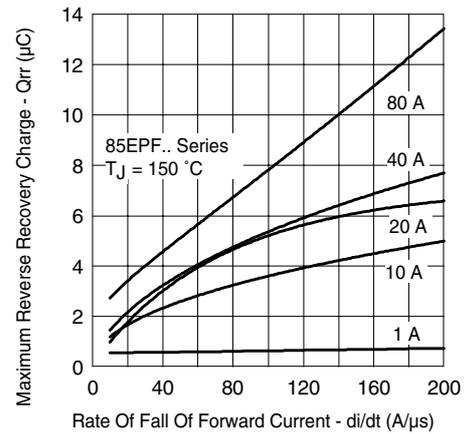


Fig. 11 - Recovery Charge Characteristics, $T_J = 150^\circ\text{C}$

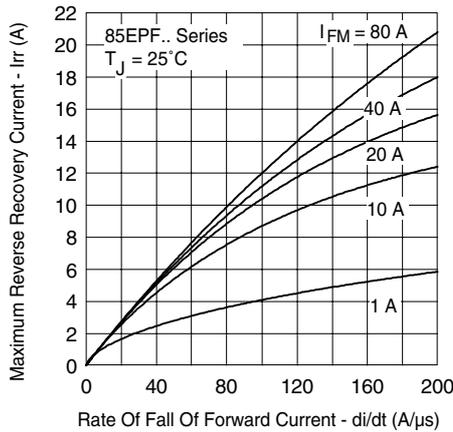


Fig. 12 - Recovery Current Characteristics, $T_J = 25^\circ\text{C}$

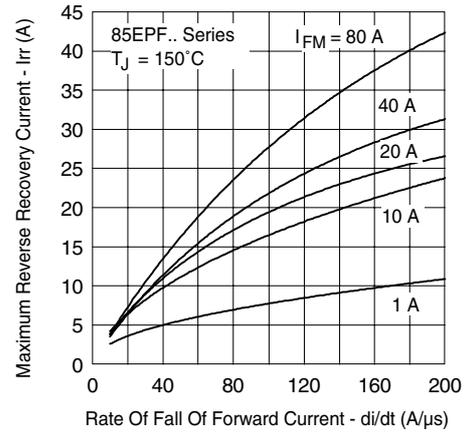


Fig. 13 - Recovery Current Characteristics, $T_J = 150^\circ\text{C}$

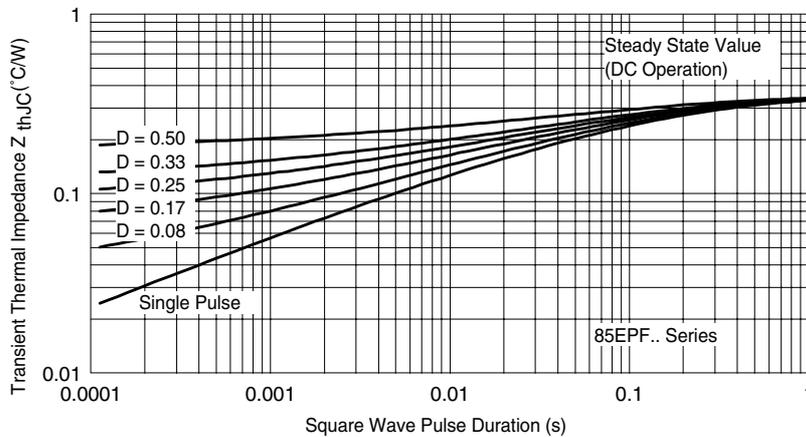
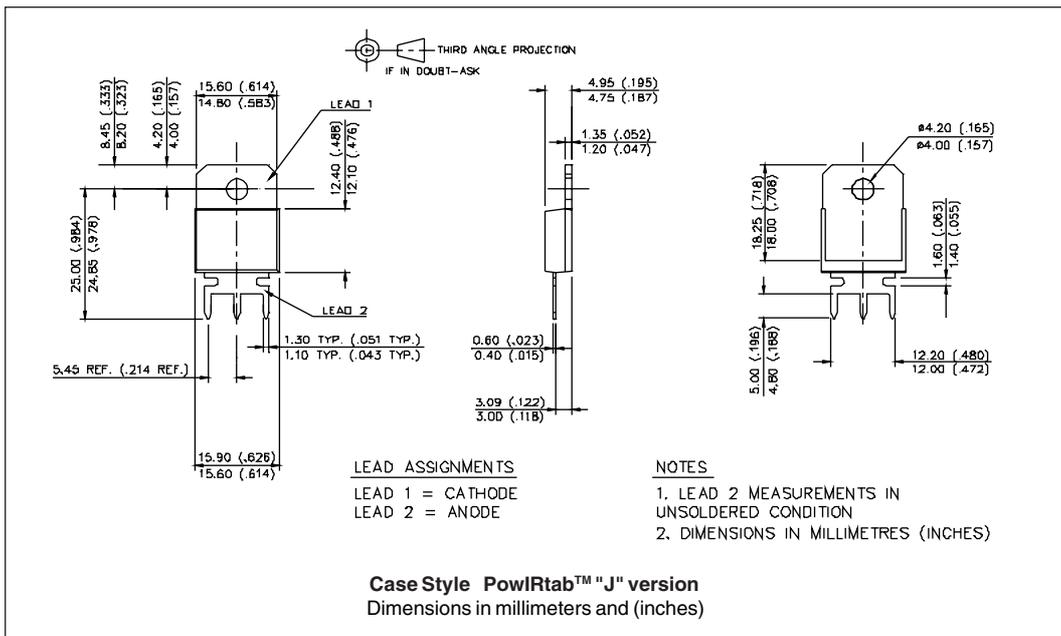
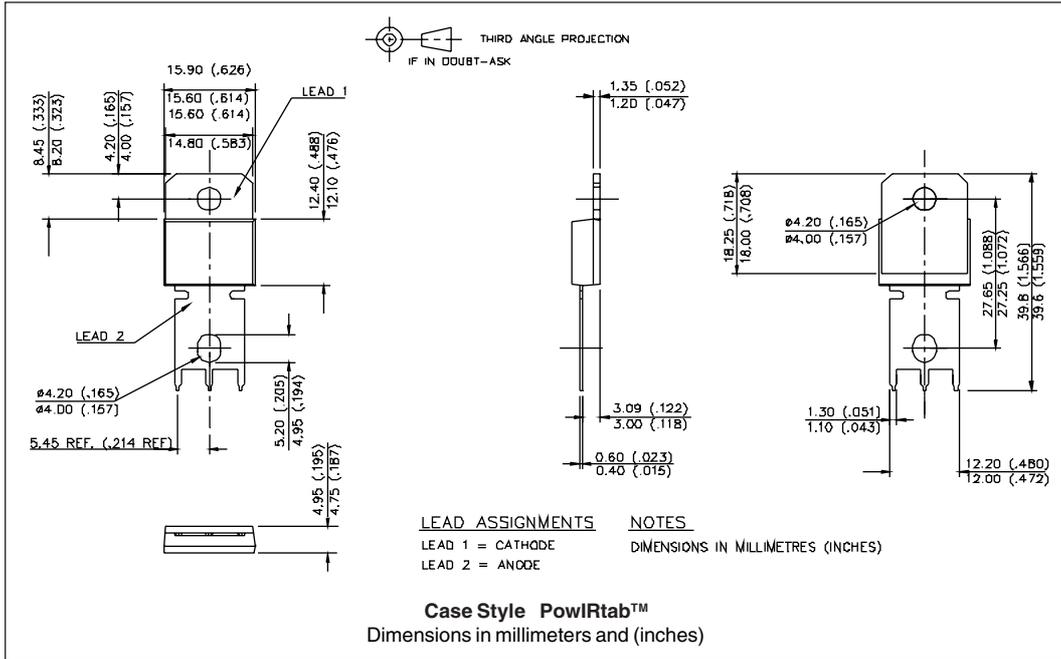


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

Outline Table



Ordering Information Table

Device Code					
85	E	P	F	06	J
①	②	③	④	⑤	⑥

<p>1 - Current Rating</p> <p>2 - Circuit Configuration: E = Single Diode</p> <p>3 - Package: P = TO-247AC</p> <p>4 - Type of Silicon: F = Fast Recovery</p> <p>5 - Voltage code: Code x 100 = V_{RRM} (*)</p> <p>6 - none=PowIRtab™ standard J = Short Lead Version</p>	<table border="1"> <tr><td>02 = 200V</td></tr> <tr><td>04 = 400V</td></tr> <tr><td>06 = 600V</td></tr> </table>	02 = 200V	04 = 400V	06 = 600V
02 = 200V				
04 = 400V				
06 = 600V				

Base Cathode
2

1 3
Anode Anode

(*) for higher voltage up to 1600V contact factory